

October 2019 Rev. 2.0.3

GENERAL DESCRIPTION

The XRP6141 is a synchronous step-down controller for point-of load supplies up to 35A. A wide 4.5V to 22V input voltage range allows for single supply operation from industry standard 5V, 12V, and 19.6V rails.

With a proprietary emulated current mode Constant On-Time (COT) control scheme, the XRP6141 provides extremely fast line and load transient response using ceramic output capacitors. It requires no loop compensation, hence simplifying circuit implementation and reducing overall component count. The control loop also provides exceptional line regulation and maintains constant operating frequency. A selectable power saving mode allows the user to operate in discontinuous mode (DCM) at light current loads, thereby significantly increasing the converter efficiency.

A host of protection features, including overcurrent, over-temperature, short-circuit, and UVLO, help achieve safe operation under abnormal operating conditions.

The XRP6141 is available in a RoHS compliant, green / halogen free space-saving 16-pin 3x3mm QFN package.

APPLICATIONS

- Networking and communications
- Fast transient Point-of-Loads
- · Industrial and medical equipment
- Embedded high power FPGA

FEATURES

- 35A capable step down controller
 - Wide input voltage range
 - 5V to 22V single supply
 - \circ 4.5V to 5.5V low V_{IN}
 - Integrated high current 2A/3A drivers
 - 0.6V to 18V adjustable output voltage

Proprietary Constant On-Time control

- No loop compensation required
- Ceramic output capacitor stable operation
- Programmable 200ns 2µs
- Constant 200kHz 800kHz frequency
- Selectable CCM or CCM / DCM operation
- Programmable hiccup current limit with thermal compensation
- Precision enable and Power-Good flag
- Programmable soft-start
- Integrated bootstrap diode
- 16-pin QFN package

TYPICAL APPLICATION DIAGRAM

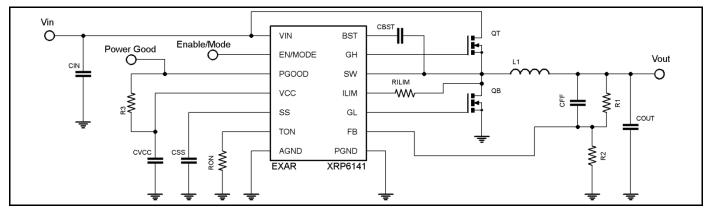


Fig. 1: XRP6141 Application Diagram



ABSOLUTE MAXIMUM RATINGS

These are stress ratings only and functional operation of the device at these ratings or any other above those indicated in the operation sections of the specifications below is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

V _{IN} 0.3V to 28	٧
V _{CC} 0.3V to 6.0	V
BST0.3V to 34\	/ 2
BST-SW0.3V to 6	V
SW, ILIM5V to 28V ¹	,2
GH0.3V to BST+0.3	V
GH-SW0.3V to 6	V
ALL other pins0.3V to VCC+0.3	V
Storage temperature65°C to 150°	C
Junction temperature150°	C
Power dissipation Internally Limite	d
Lead temperature (Soldering, 10 sec) 300°	C
ESD rating (HBM - Human Body Model) 2k	V

OPERATING RATINGS

V _{IN}	0.3V to 22V
V _{CC}	0.3V to 5.5V
SW, ILIM	1V to 26V ¹
PGOOD, VCC, TON, SS, EN, GL, FB	0.3V to 5.5V
Switching frequency	200kHz - 800kHz ³
Junction temperature range	40°C to 125°C

Note 1: SW pin's minimum DC range is -1V, transient is

-5V for less than 50ns

Note 2: No external voltage applied

Note 3: Recommended

ELECTRICAL SPECIFICATIONS

Specifications are for the operating junction temperature of $T_J = 25^{\circ}\text{C}$ only; limits applying over the full operating junction temperature range are denoted by a "•". Minimum and maximum limits are guaranteed through test, design, or statistical correlation. Typical values represent the most likely parametric norm at $T_J = 25^{\circ}\text{C}$, and are provided for reference purposes only. Unless otherwise indicated, $V_{IN} = 12V$, BST = VCC, SW = GND = PGND = 0V, CGH = CGL = 3.3nF.

Parameter	Min.	Тур.	Max.	Units		Conditions
Power Supply Characteristics						,
V input voltage range	5	12	22	V		VCC regulating
V _{IN} , input voltage range	4.5	5.0	5.5	V	Ů	VCC tied to V _{IN}
I_{VIN} , V_{IN} supply current		0.7	2	mA	•	Not switching, $V_{IN} = 12V$, VFB = 0.7V
I _{VCC} , VCC quiescent current		0.7	2	mΑ	•	Not switching, $V_{CC} = V_{IN} = 5V$, VFB = 0.7V
I_{VIN} , V_{IN} supply current		11		mA		f = 300kHz, RON = 108.8k, VFB = 0.58V
I _{OFF} , shutdown current		0.1		μΑ		Enable = $0V$, $V_{IN} = 12V$
Enable and Under-Voltage Lock	-Out UVL	.0				
V _{IH_EN} , EN pin rising threshold	1.8	1.9	2.0	V	•	
V _{EN_HYS} , EN pin hysteresis		50		mV		
V _{IH_EN} , EN pin rising threshold for DCM/CCM operation	2.9	3.0	3.1	V	•	
V _{EN_HYS} , EN pin hysteresis		100		mV		
VCC UVLO start threshold, rising edge	4.00	4.25	4.50	V	•	
VCC UVLO hysteresis		200		mV		
Reference Voltage						
	0.597	0.600	0.603	V		$V_{IN} = 5V-22V \rightarrow VCC regulating$
V _{REF} , reference voltage	0.596		0.604	V		$V_{IN} = 4.5V-5.5V \rightarrow tie VCC to V_{IN}$
	0.594	0.600	0.606	V	•	$V_{IN} = 5V-22V \rightarrow VCC \text{ regulating,}$ $V_{IN} = 4.5V-5.5V \rightarrow \text{tie VCC to } V_{IN}$
DC line regulation		±0.1		%		ССМ operation, closed loop, applies to any Соит
DC load regulation		±0.25		%		CCM operation, closed loop, applies to any C _{OUT}



Parameter	Min.	Тур.	Max.	Units		Conditions
Programmable Constant On-Tim	ne	7.				
On-time 1	1855	2182	2509	ns	•	$RON = 141.2k\Omega$, $V_{IN} = 22V$
f corresponding to on-time 1	217	250	294	kHz		$V_{IN} = 22V$, $V_{OUT} = 12V$
Minimum programmable on-time		109		ns		$RON = 7.059k\Omega$, $V_{IN} = 22V$
On-time 2	170	200	230	ns	•	$RON = 7.059k\Omega$, $V_{IN} = 12V$
f corresponding to on-time 2	1618	1375	1196	kHz		V _{OUT} = 3.3V
f corresponding to on-time 2	490	417	362	kHz		V _{OUT} = 1.0V
On-time 3	391	460	529	ns	•	RON = $16.235k\Omega$, $V_{IN} = 12V$
Minimum off-time		250	350	ns	•	
Diode Emulation Mode						
Zero crossing threshold	-4	-1		mV		DC value measured during test
Soft-Start						
SS charge current	-14	-10	-6	μΑ	•	
SS discharge current	1			mA	•	Fault present
VCC Linear Regulator (VCC should	d be tied	to V _{IN} , f	or 4.5V	≤V _{IN} ≤5.	5V)	
VCC output voltage	4.8	5.0	5.2	V	•	$V_{IN} = 6V$ to 22V, Iload = 0 to 30mA
vec output voltage	4.51	4.7		V	•	$V_{IN} = 5V$, Iload = 0 to 20mA
Dropout voltage		200	490	mV	•	$I_{VCC} = 30mA$
Power Good Output						
Power Good threshold	-10	-7.5	-5	%		
Power Good hysteresis		2	4	%		
Power Good sink current	1			mA		
Protection: OCP, OTP, Short-circ	cuit					
Hiccup timeout		110		ms		
ILIM pin source current	45	50	55	μΑ		
ILIM current temperature coefficient		0.4		%/°C		
OCP comparator offset	-8	0	+8	mV	•	
Current limit blanking		100		ns		GL rising > 1V
Thermal shutdown threshold ¹		150		°C		Rising temperature
Thermal hysteresis ¹		15		°C		
VSCTH feedback pin short-circuit threshold	50	60	70	%	•	Percent of VREF, short circuit is active after PGOOD is up
Output Gate drivers						
GH pull-down resistance		1.35	2.0	Ω		IGH = 200mA
GH pull-up resistance		1.8	2.8	Ω		IGH = 200mA
GL pull-down resistance		1.35	1.9	Ω		IGL = 200mA
GL pull-up resistance		1.7	2.7	Ω		IGL = 200mA
GH and GL pull-down resistance		50		kΩ		
GH and GL rise time		35	50	ns		10% to 90%
GH and GL fall time		30	40	ns		90% to 10%
GL to GH non-overlap time	20	30	60	ns		Measured GL falling edge = 1V to GH rising edge = 1V, BST = VCC, SW = 0V
GH to GL non-overlap time	15	20	40	ns		Measured GH falling edge = 1V to GL rising edge = 1V

Note 1: Guaranteed by design



BLOCK DIAGRAM

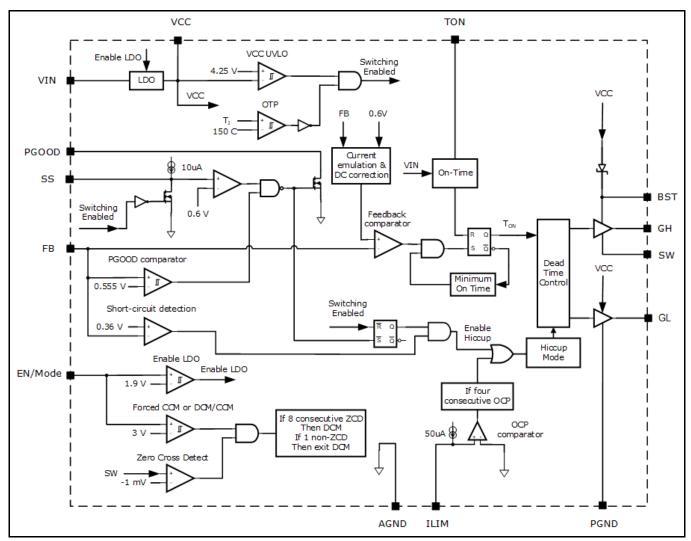


Fig. 2: XRP6141 Block Diagram

PIN ASSIGNMENT

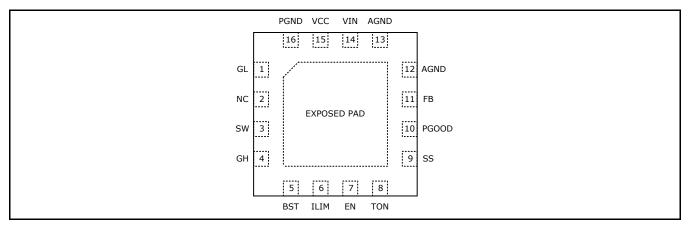


Fig. 3: XRP6141 Pin Assignment



PIN DESCRIPTION

Name	Pin Number	Description				
GL	1	Driver output for Low-side N-channel synchronous MOSFET.				
NC	2	Internally not connected. Leave this pin floating.				
SW	3	Lower supply rail for high-side gate driver GH. Connect this pin to the junction between the two external N-channel MOSFETs.				
GH	4	Driver output for high-side N-channel switching MOSFET.				
BST	5	High-side driver supply pin. Connect a 0.1µF bootstrap capacitor between BST and SW.				
ILIM	6	Over-current protection programming. Connect with a resistor to the drain of the low-side MOSFET.				
EN/MODE	7	Precision enable pin. Pulling this pin above 1.9V will turn the IC on and it will operate in Forced CCM. If the voltage is raised above 3.0V, then the IC will operate in DCM or CCM, depending on load.				
TON	8	Constant on-time programming pin. Connect with a resistor to AGND.				
SS	9	Soft-start pin. Connect an external capacitor between SS and AGND to program the soft-start rate based on the 10µA internal source current.				
PGOOD	10	Power-good output. This open-drain output is pulled low when V_{OUT} is outside the regulation.				
FB	11	Feedback input to feedback comparator. Connect with a set of resistors to VOUT and GND in order to program V_{OUT} .				
AGND	12, 13	Analog ground. Control circuitry of the IC is referenced to this pin.				
VIN	14	IC supply input. Provides power to internal LDO.				
VCC	15	The output of LDO. For operation using a 5V rail, VCC should be shorted to VIN.				
PGND	16	Low side driver ground.				
Exposed Pad		Thermal pad for heat dissipation. Connect to AGND with a short trace.				

ORDERING INFORMATION(1)

Part Number	Operating Temperature Range	Package	Packing Method	Lead-Free		
XRP6141ELTR-F	-40°C ≤ T _J ≤ +125°C	3x3mm QFN16	Tape & Reel	Yes ⁽²⁾		
XRP6141EVB	XRP6141 Evaluation Board					

NOTES:

- 1. Refer to www.maxlinear.com/XRP6141 for most up-to-date Ordering Information
- 2. Visit <u>www.maxlinear.com</u> for additional information on Environmental Rating.



TYPICAL PERFORMANCE CHARACTERISTICS

All data taken at $V_{IN} = 12V$, $V_{OUT} = 1.2V$, f = 300 kHz, $T_A = 25$ °C, unless otherwise specified - schematic and BOM from Application Information section of this datasheet.

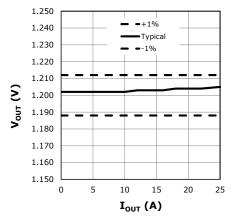


Fig. 4: Load Regulation, $V_{IN} = 12V$

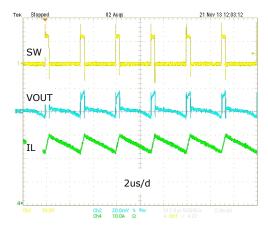


Fig. 6: Vout Ripple is 22mV at 25A, 12VIN, 1.2VOUT

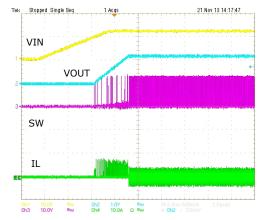


Fig. 8: Powerup, Forced CCM, $I_{OUT} = 0A$

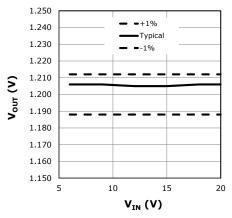


Fig. 5: Line Regulation, $I_{OUT} = 25A$

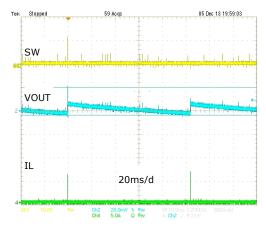


Fig. 7: V_{OUT} Ripple is 22mV at 0A, DCM, 12 V_{IN} , 1.2 V_{OUT}

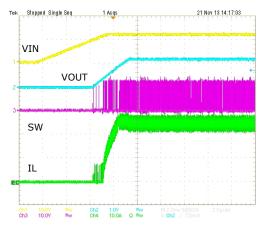


Fig. 9: Powerup, Forced CCM, $I_{OUT} = 25A$



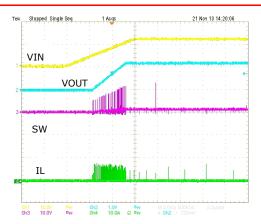


Fig. 10: Powerup, DCM / CCM, $I_{OUT} = 0A$

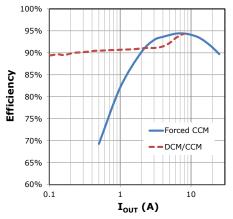


Fig. 12: Efficiency, $5V_{IN}$, $1.8V_{OUT}$, $0.47\mu H$, 300kHz

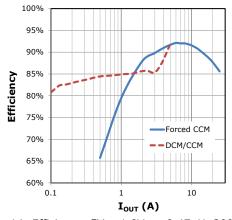


Fig. 14: Efficiency, $5V_{IN}$, $1.0V_{OUT}$, $0.47\mu H$, 300kHz

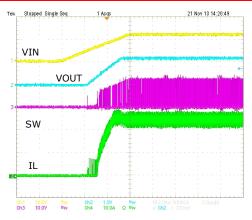


Fig. 11: Powerup, DCM / CCM, $I_{OUT} = 25A$

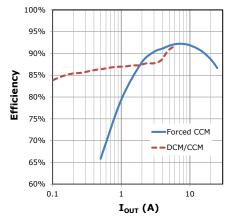


Fig. 13: Efficiency, $5V_{IN}$, $1.2V_{OUT}$, $0.47\mu H$, 300kHz

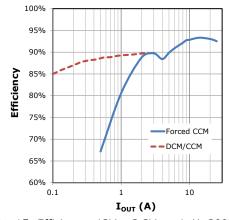


Fig. 15: Efficiency, $12V_{\text{IN}}$, $3.3V_{\text{OUT}}$, $1\mu\text{H}$, 300kHz



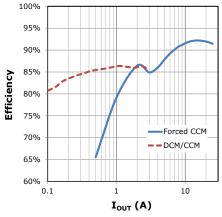


Fig. 16: Efficiency, $12V_{IN}$, $2.5V_{OUT}$, $1\mu H$, 300kHz

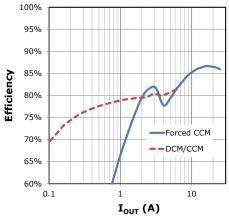


Fig. 18: Efficiency, $12V_{IN}$, $1.2V_{OUT}$, $0.47\mu H$, 300kHz

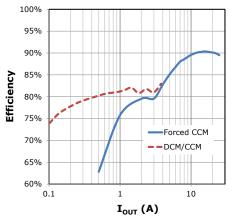


Fig. 17: Efficiency, $12V_{\text{IN}}$, $1.8V_{\text{OUT}}$, $1\mu\text{H}$, 300kHz

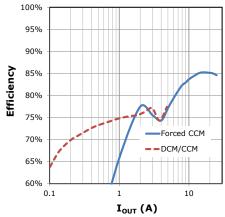


Fig. 19: Efficiency, $12V_{IN}$, $1.0V_{OUT}$, $0.47\mu H$, 300kHz

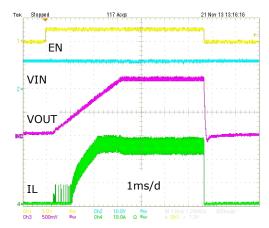


Fig. 20: Enable Turn On / Turn Off, $12V_{IN}$, $1.2V_{OUT}$, 25A



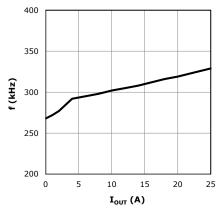


Fig. 22: Frequency versus I_{OUT} , Forced CCM

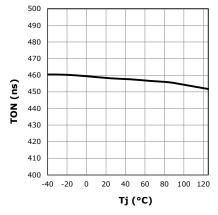


Fig. 24: On-Time versus Temperature

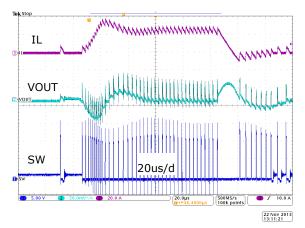


Fig. 26: Load Step, DCM/CCM, 0A-25A-0A

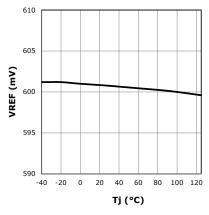


Fig. 23: VREF versus Temperature

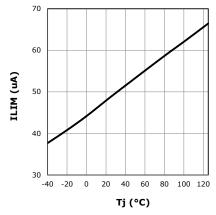


Fig. 25: ILIM versus Temperature

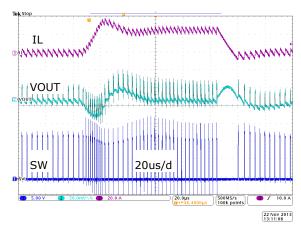


Fig. 27: Load Step, Forced CCM, 0A-25A-0A



DETAILED OPERATION

XRP6141 is a synchronous step-down, proprietary emulated, current-mode Constant On-Time (COT) controller. The on-time, which is programmed via RON, is inversely proportional to $V_{\rm IN}$ and maintains a nearly constant frequency. The emulated current-mode control allows the use of ceramic output capacitors.

Each switching cycle begins with the GH signal turning the high-side (switching) FET for a pre-programmed time. At the end of the on-time, the high-side FET is turned off and the low-side (synchronous) FET is turned on for a preset minimum time (250ns nominal). This parameter is termed Minimum Off-Time. After the Minimum Off-Time, the voltage at the feedback pin FB is compared to an internal voltage ramp at the feedback comparator. When VFB drops below the ramp voltage, the high-side FET is turned on and the cycle repeats. This voltage ramp constitutes an emulated current ramp and makes possible the use of ceramic capacitors, in addition to other capacitor types, for output filtering.

ENABLE/MODE INPUT (EN/MODE)

The EN/MODE pin accepts a tri-level signal that is used to control turn on and off. It also selects between two modes of operation: 'Forced CCM' and 'DCM / CCM'. If EN is pulled below 1.9V, the controller shuts down. A voltage between 1.9V and 3.0V selects the Forced CCM Mode, which will run the converter in continuous conduction at all times. A voltage higher than 3.0V selects the DCM / CCM Mode, which will run the converter in discontinuous conduction at light loads.

Selecting the Forced CCM Mode

In order to set the controller to operate in Forced CCM, a voltage between 1.9V and 3.0V must be applied to the EN/MODE pin. This can be achieved with an external control signal that meets the above voltage requirement. Where an external control is not available, the EN/MODE can be derived from $V_{\rm IN}.$ If $V_{\rm IN}$ is well regulated, use a resistor divider and set the voltage to 2.5V. If $V_{\rm IN}$ varies over a wide range, the circuit shown in Figure 28 can be used to generate the required voltage. Note that at $V_{\rm IN}$ of 5.5V to 22V, the nominal Zener voltage is 4.0V to 5.0V respectively. Therefore, for $V_{\rm IN}$ in the range of 5.5V to 22V, the circuit shown in Figure 28 will generate voltage at the EN/MODE pin required for Forced CCM.

Selecting the DCM/CCM Mode

In order to set the controller operation to DCM / CCM, a voltage between 3.1V and 5.5V must be applied to the EN/MODE pin. If an external control signal is available, it can be directly connected to the EN/MODE pin. In applications where an external control signal is not available, the EN/MODE input can be derived from $V_{\rm IN}$. If $V_{\rm IN}$ is well regulated, use a resistor divider and set the voltage to 4V. If $V_{\rm IN}$ varies over a wide range, the circuit shown in Figure 29 can be used to generate the required voltage.

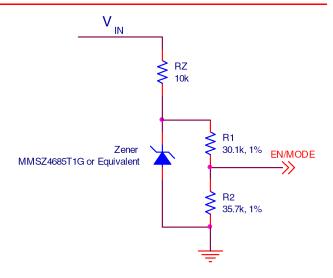


Figure 28. Selecting Forced CCM by Deriving EN/MODE from $V_{\rm IN}$

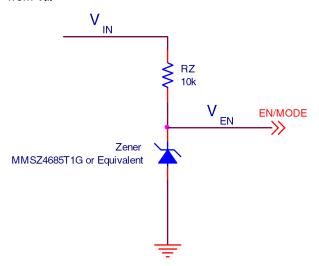


Figure 29. Selecting DCM / CCM by Deriving EN/MODE from $V_{\rm IN}\,$

PROGRAMMING THE ON-TIME

The on-time TON is programmed via resistor RON according to following equation:

$$TON = \frac{(3.4E - 10) \times RON}{VIN}$$

The required TON for a given application is calculated from:

$$TON = \frac{VOUT}{VIN \times f}$$



Note that switching frequency f will increase somewhat, as a function of increasing load current and increasing losses (see Figure 22).

OVER-CURRENT PROTECTION (OCP)

If load current exceeds the programmed over-current I_{OCP} for four consecutive switching cycles, then the IC enters hiccup mode of operation. In hiccup, the MOSFET gates are turned off for 110ms (hiccup timeout). Following the hiccup timeout, a soft-start is attempted. If OCP persists, hiccup timeout will repeat. The IC will remain in hiccup mode until load current is reduced below the programmed $I_{\text{OCP}}.$ In order to program over-current protection, use the following equation:

$$RLIM = \frac{(IOCP \times RDS) + 8mV}{ILIM}$$

Where:

RLIM is resistor value for programming I_{OCP}

 I_{OCP} is the over-current value to be programmed

RDS is the MOSFET rated on resistance

8mV is the OCP comparator offset

 I_{LIM} is the internal current that generates the necessary OCP comparator threshold (use $45\mu A)$

Note that I_{LIM} has a positive temperature coefficient of 0.4%/°C. This is meant to roughly match and compensate for positive temperature coefficient of the synchronous FET. In order for this feature to be effective, the temperature rise of the IC should approximately match the temperature rise of the FET.

SHORT-CIRCUIT PROTECTION (SCP)

If the output voltage drops below 60% of its programmed value, the IC will enter hiccup mode. Hiccup will persist until the short-circuit is removed. The SCP circuit becomes active after PGOOD asserts high.

OVER-TEMPERATURE PROTECTION (OTP)

OTP triggers at a nominal die temperature of 150°C. The gate of switching FET and synchronous FET are turned off. When die temperature cools down to 135°C, soft-start is initiated and operation resumes.

PROGRAMMING THE OUTPUT VOLTAGE

Use an external voltage divider as shown in Figure 1 to program the output voltage VOUT.

$$R1 = R2 \times \left(\frac{VOUT}{0.6} - 1\right)$$

The R2 recommended range is $2k\Omega$ to $10k\Omega$.

PROGRAMMING THE SOFT-START

Place a capacitor CSS between the SS and GND pins to program the soft-start. In order to program a soft-start time of TSS, calculate the required capacitance CSS from the following equation:

$$CSS = TSS \times \frac{10uA}{0.6V}$$

FEED-FORWARD CAPACITOR (C_{FF})

A feed-forward capacitor (C_{FF}) may be necessary depending on the Equivalent Series Resistance (ESR) of C_{OUT} . If only ceramic output capacitors are used, then a C_{FF} is necessary. Calculate C_{FF} from:

$$CFF = \frac{1}{2 \times \pi \times R1 \times 7 \times fLC}$$

where:

R1 is the resistor that CFF is placed in parallel with

 f_{LC} is the frequency of the output filer double pole

 f_{LC} must be less than 15kHz when using ceramic C_{OUT} . If necessary, increase C_{OUT} and/or L in order to meet this constraint.

When using capacitors with higher ESR such as the Panasonic TPE series, a C_{FF} is not required provided the following conditions are met:

- 1. The frequency of the output LC double pole f_{LC} should be less than 10kHz.
- 2. The frequency of ESR zero $f_{ZERO,ESR}$ should be at least five times larger than f_{LC} .

Note that if $f_{\text{ZERO},\text{ESR}}$ is less than 5 x f_{LC} , then it is recommended to set the f_{LC} at less than 2kHz. C_{FF} is still not required.

FEED-FORWARD RESISTOR (RFF)

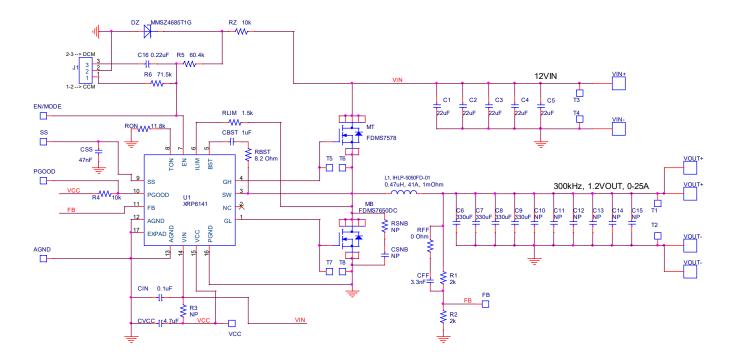
Poor PCB layout and/or extremely fast switching FETs can cause switching noise at the output and may couple to the FB pin via C_{FF} . Excessive noise at FB will cause poor load regulation. To solve this problem, place a resistor R_{FF} in series with C_{FF} . A R_{FF} value up to 2% of R1 is acceptable.

MAXIMUM ALLOWABLE VOLTAGE RIPPLE AT FB PIN

Note that the steady-state voltage ripple at feedback pin $(V_{FB,RIPPLE})$ must not exceed 50mV in order for the controller to function correctly. If $V_{FB,RIPPLE}$ is larger than 50mV, then C_{OUT} should be increased as necessary in order to keep the $V_{FB,RIPPLE}$ below 50mV.



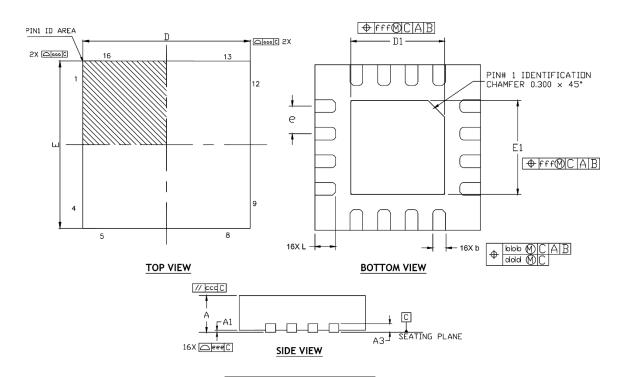
Applications Circuit





MECHANICAL DIMENSIONS

16 PIN 3X3 QFN



DIMENSION TABLE							
SYMBOL	MIN	NOM	MAX				
Α	0.80	0.90	1.00				
A1	0.00	0.02	0.05				
A3	0.20Ref						
b	0.18	0.30					
D	3.00 BSC						
E	3.00 BSC						
е	0.50 BSC						
D1	1.50	1.65	1.80				
E1	1.50	1.65	1.80				
L	0.20	0.30	0.40				
K	0.20	_					
aaa		0.15					
bbb		0.10					
ccc		0.10					
ddd		0.05					
eee		0.08					
fff		0.10					
N		16					

TERMINAL DETAILS

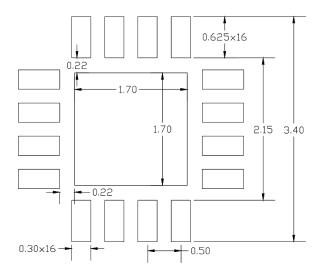
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS AND TOLERANCE PER JEDEC MO-220.

Drawing No.: POD- 00000138

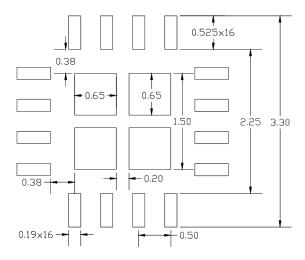
Revision: A



RECOMMENDED LAND PATTERN AND STENCIL



TYPICAL RECOMMENDED LAND PATTERN



TYPICAL RECOMMENDED STENCIL

Drawing No.: POD- 00000138

Revision: A